



175BGQ030 175BGQ030J

SCHOTTKY RECTIFIER

175 Amp

Major Ratings and Characteristics

Characteristics	175BGQ030	Units
$I_{F(AV)}$ Rectangular waveform @ T_C	175	A
	115	°C
I_{DC} Maximum	248	A
V_{RRM}	30	V
I_{FSM} @ $t_p = 5 \mu s$ sine	8000	A
V_F @ 175A pk typical @ T_J	0.45	V
	150	°C
T_J range	-55 to 150	°C

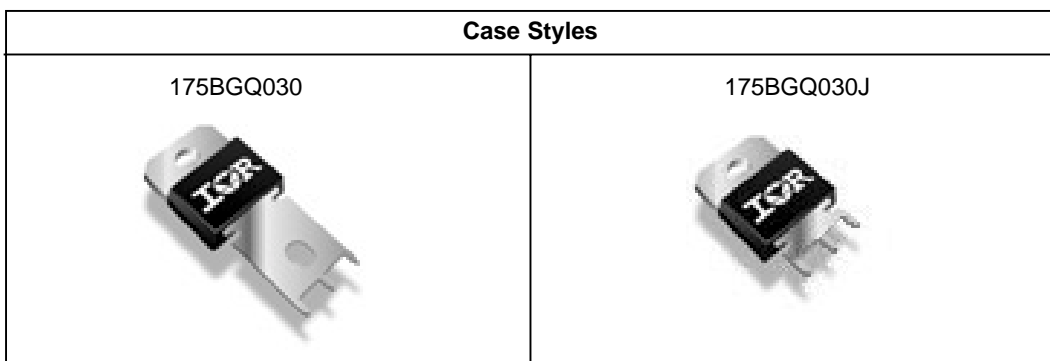
Description/ Features

The 175BGQ030 Schottky rectifier has been optimized for ultra low forward voltage drop specifically for low voltage output in high current AC/DC power supplies.

The proprietary barrier technology allows for reliable operation up to 150°C junction temperature. Typical applications are in switching power supplies, converters, reverse battery protection, and redundant power subsystems.

- 150°C T_J operation
- High Frequency Operation
- Ultra low forward voltage drop
- Continuous High Current operation
- Guard ring for enhanced ruggedness and long term reliability
- **PowIRtab™ package**

Case Styles



175BGQ030, 175BGQ030J

Bulletin PD-20997 rev. E 12/02



Voltage Ratings

Part number	175BGQ030
V _R Max. DC Reverse Voltage (V)	30
V _{RWM} Max. Working Peak Reverse Voltage (V)	

Absolute Maximum Ratings

Parameters	175BGQ	Units	Conditions
I _{F(AV)} Max. Average Forward Current	175	A	50% duty cycle @ T _C = 115°C, rectangular wave form
I _{F(RMS)} RMS Forward Current	248	A	T _C = 114°C
I _{FSM} Max. Peak One Cycle Non-Repetitive Surge Current	8000	A	5µs Sine or 3µs Rect. pulse
	1500		10ms Sine or 6ms Rect. pulse
E _{AS} Non-Repetitive Avalanche Energy	80	mJ	T _J = 25°C, I _{AS} = 12 Amps, L = 1.12 mH
I _{AR} Repetitive Avalanche Current	12	A	Current decaying linearly to zero in 1µsec Frequency limited by T _J max. V _A = 1.5 x V _R typical

Electrical Specifications

Parameters	175BGQ		Units	Conditions	
	Typ.	Max.			
V _{FM} Forward Voltage Drop (1) (2)	0.46	0.48	V	@ 100A	T _J = 25°C
	0.53	0.56	V	@ 175A	
	0.35	0.38	V	@ 100A	T _J = 150°C
	0.45	0.49	V	@ 175A	
I _{RM} Reverse Leakage Current (1)	1.3	4.5	mA	T _J = 25°C	V _R = rated V _R
	450	650	mA	T _J = 125°C	
	160	220	mA	T _J = 125°C	V _R = 15V
	1400	2000	mA	T _J = 150°C	V _R = 30V
V _{F(TO)} Threshold Voltage	0.242		V	T _J = T _J max.	
r _t Forward Slope Resistance	1.4		mΩ		
C _T Max. Junction Capacitance	8500		pF	V _R = 5V _{DC} , (test signal range 100Khz to 1Mhz) 25°C	
L _S Typical Series Inductance	3.5		nH	Measured from tab to mounting plane	
dv/dt Max. Voltage Rate of Change (Rated V _R)	10000		V/µs		

(1) Pulse Width < 300µs, Duty Cycle < 2%

(2) V_{FM} = V_{F(TO)} + r_t x I_F

Thermal-Mechanical Specifications

Parameters	175BGQ	Units	Conditions
T _J Max. Junction Temperature Range	-55 to 150	°C	
T _{stg} Max. Storage Temperature Range	-55 to 150	°C	
R _{thJC} Max. Thermal Resistance Junction to Case	0.25	°C/W	DC operation
R _{thCS} Typical Thermal Resistance, Case to Heatsink	0.20	°C/W	Mounting surface, smooth and greased
wt Approximate Weight	5(0.18)	g(oz.)	
T Mounting Torque	Min.	1.2(10)	N*m (lbf-in)
	Max.	2.4(20)	
Case Style	PowIRtab™		

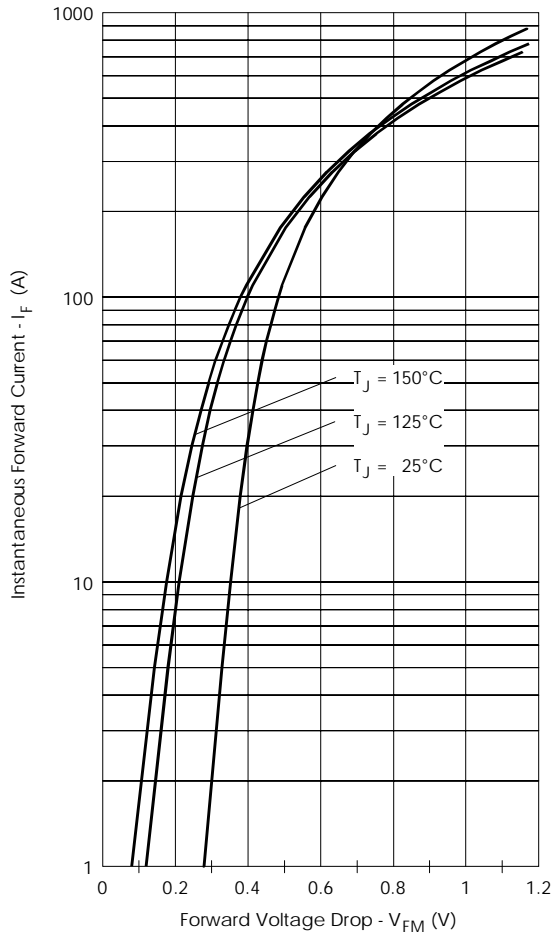


Fig. 1 - Maximum Forward Voltage Drop Characteristics

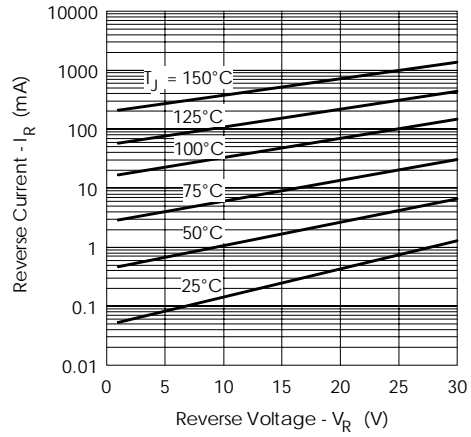


Fig. 2 - Typical Values of Reverse Current Vs. Reverse Voltage

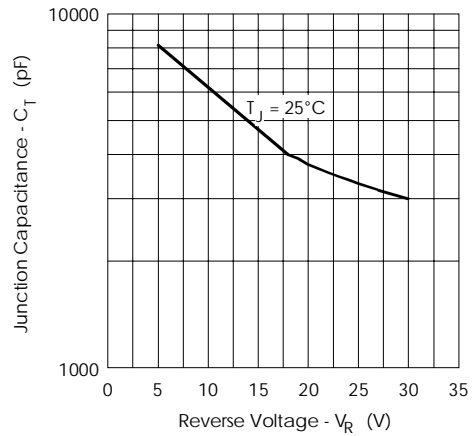


Fig. 3 - Typical Junction Capacitance Vs. Reverse Voltage

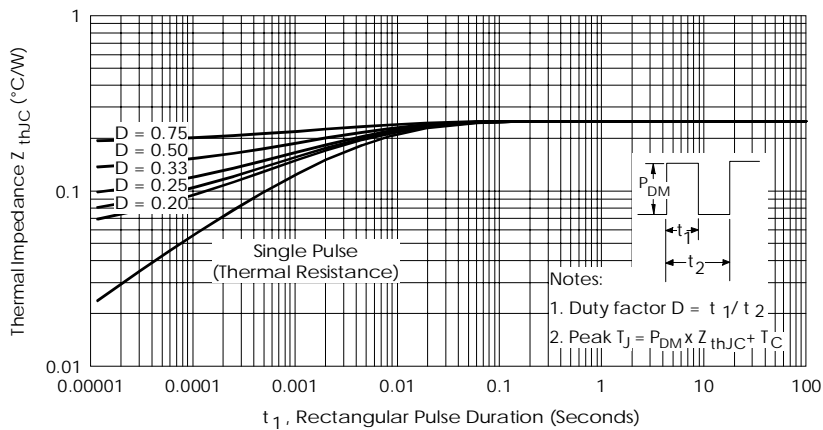


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

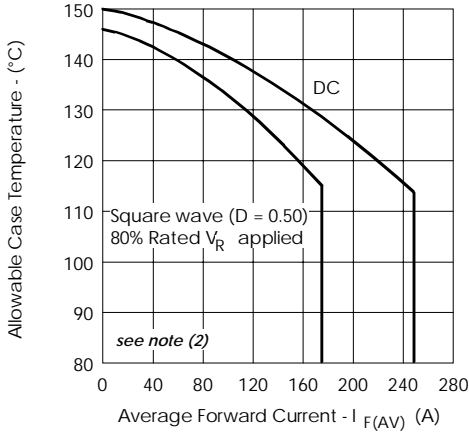


Fig.5- Maximum Allowable Case Temperature Vs. Average Forward Current

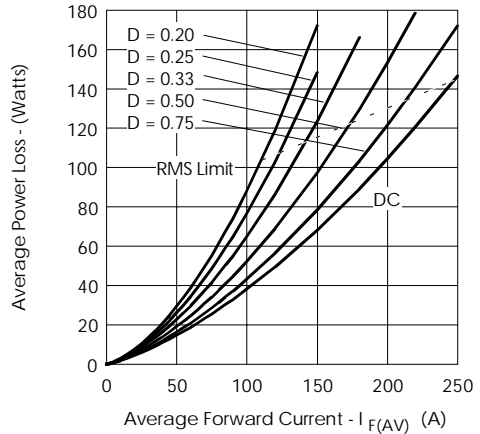


Fig.6- Forward Power Loss Characteristics

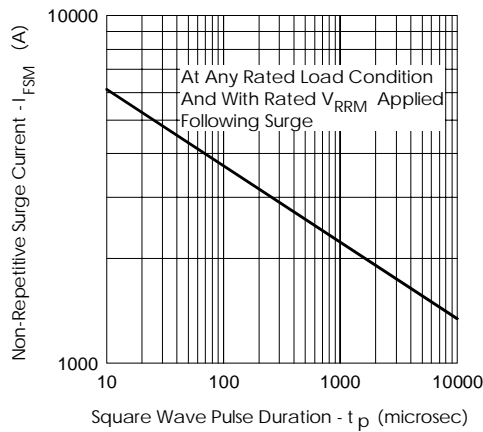


Fig.7- Maximum Non-Repetitive Surge Current

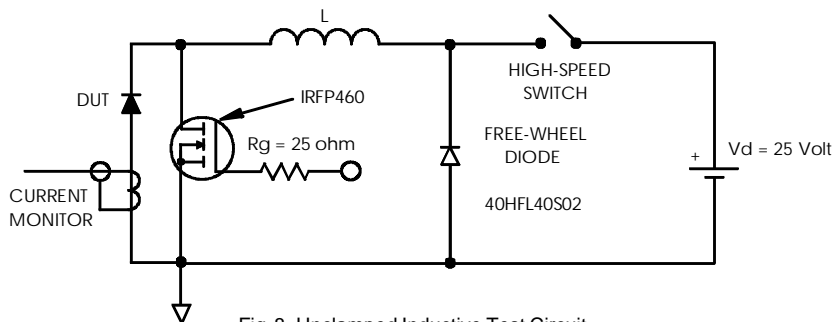


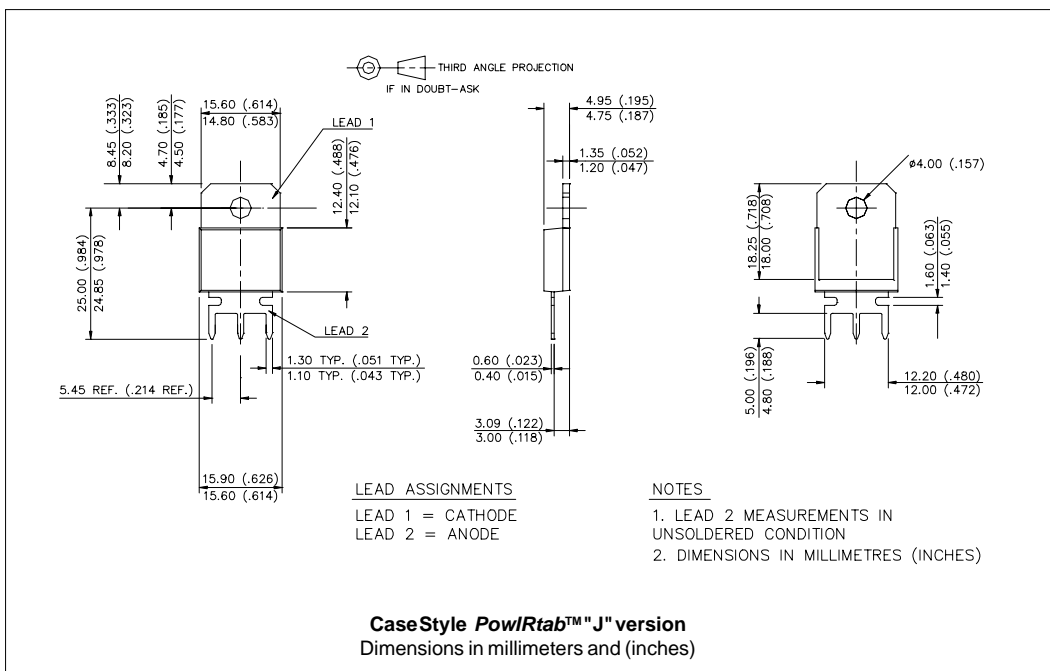
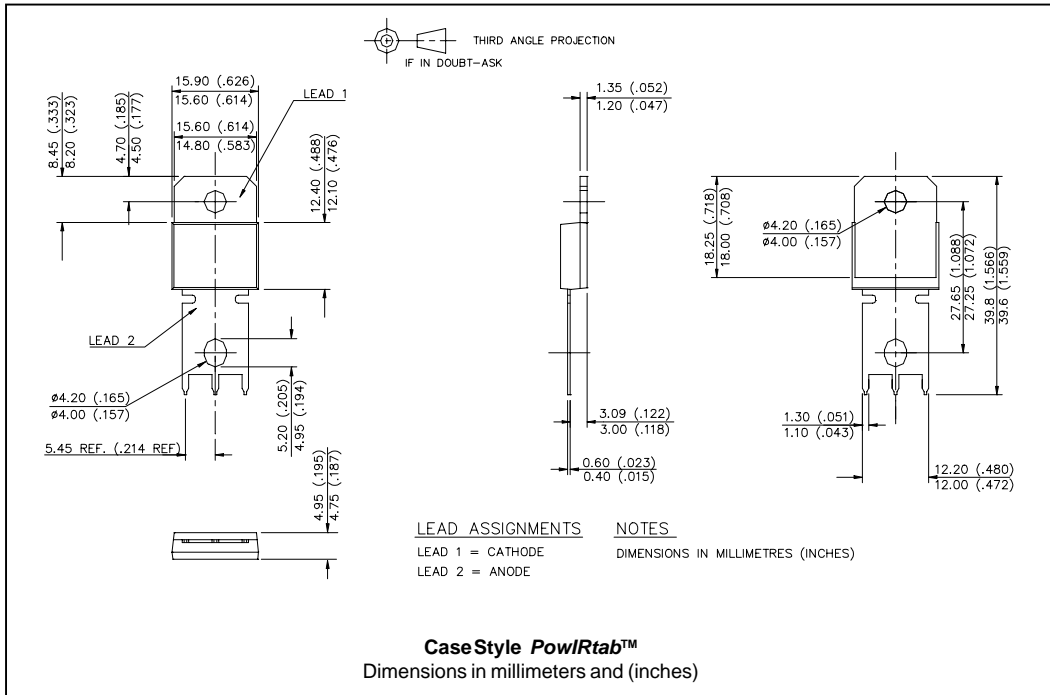
Fig.8- Unclamped Inductive Test Circuit

(3) Formula used: $T_c = T_j - (P_d + P_{d_{REV}}) \times R_{thJC}$;

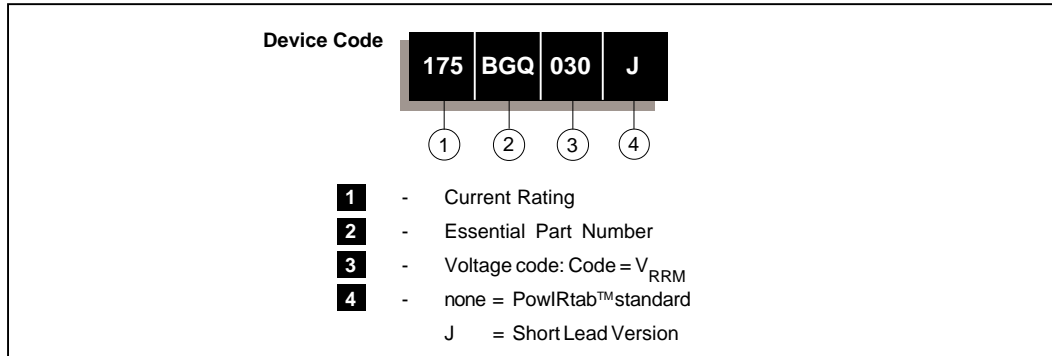
$P_d =$ Forward Power Loss = $I_{F(AV)} \times V_{FM} @ (I_{F(AV)} / D)$ (see Fig. 6);

$P_{d_{REV}} =$ Inverse Power Loss = $V_{R1} \times I_R (1 - D)$; $I_R @ V_{R1} = 80\%$ rated V_R

Outline Table



Ordering Information Table



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*****
This model has been developed by
Wizard SPICE MODEL GENERATOR(1999)
(International Rectifier Corporation)
contains Proprietary Information
*****
SPICE Model Diode is composed by a
simple diode plus paralld VCG2T
*****

.SUBCKT 175bgq30 ANO CAT
D1 ANO 1 DMOD (0.24359)
*Define diode model
.MODEL DMOD D(IS=1.3875007809205E-04A,N=1.00125798542747,BV=30V,
+IBV=0.160931851779476A,RS=0.0001656412,CJO=5.05942026644635E-08,
+VJ=1.99501834690192,XTI=2,EG=0.711439066978857)
*****
*Implementation of VCG2T
VX 1 2 DC 0V
R1 2 CAT TRES 1E-6
.MODEL TRES RES(R=1,TC1=4.01799427965033)
GP1 ANO CAT VALUE={-ABS(I(VX))*(EXP(((((-3.827089E-03/
4.017994)*((V(2,CAT)*1E6)/(I(VX)+1E-6)-1))+1)*0.122401*ABS(V(ANO,CAT)))-1)}
*****
.ENDS 175bgq30

Thermal Model Subcircuit
.SUBCKT 175bgq30T 5 1
CTHERM1 5 4 1.30E+3
CTHERM2 4 3 2.87E+2
CTHERM3 3 2 1.56E+4
CTHERM4 2 1 2.37E+5

R THERM1 5 4 3.13E-2
R THERM2 4 3 1.42E-1
R THERM3 3 2 6.70E-2
R THERM4 2 1 1.72E-4

.ENDS 175bgq30T
    
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Data and specifications subject to change without notice.
This product has been designed and qualified for Industrial Level.
Qualification Standards can be found on IR's Web site.

International
IOR Rectifier

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